

1MHz, 2A Step-Up Current Mode PWM Converter

General Description

The AP8660 is a current mode boost DC-DC converter. Its PWM circuitry with built-in 0.25Ω power MOSFET make this regulator highly power efficient. The internal compensation network also minimizes as much as 6 external component counts. The non-inverting input of error amplifier connects to a 0.6V precision reference voltage and internal soft-start function can reduce the inrush current.

The AP8660 is available in the SOT23-6L package and provides space-saving PCB for the application fields.

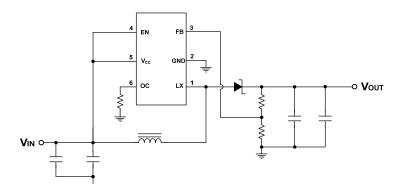
Features

- > Adjustable Output up to 24V
- > Internal Fixed PWM frequency: 1.0MHz
- > Precision Feedback Reference Voltage: 0.6V (±2%)
- > Internal 0.25Ω, 2A, 26V Power MOSFET
- ➤ Shutdown Current: 0.1µA
- > Over Voltage Protection
- > Over Temperature Protection
- ➤ Adjustable Over Current Protection: 0.5A ~ 2.5A
- Package: SOT23-6L

Applications

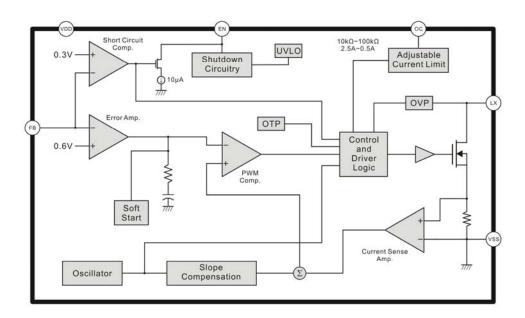
- > Chargers
- > LCD Displays
- Digital Cameras
- > Handheld Devices
- > Portable Products

Typical Application Circuit



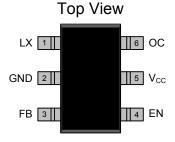


Function Block Diagram



Pin Descriptions

SOT23-6L



Name	No.	1/0	Description	
LX	1	0	Power Switch Output	
GND	2	Р	IC Ground	
FB	3	I	Error Amplifier Inverting Input	
EN	4	I	Enable Control (Active High)	
V _{CC}	5	Р	IC Power Supply	
OC	6	Ī	Adjustable Current Limit (Floating Available)	



Ordering Information

Part Number	Code	Operating Temperature	Package	MOQ	Description	
AP8660R-G1 AL 6		6 -40°C ~ 85°C	SOT23-6L	3000EA	Tape & Reel	

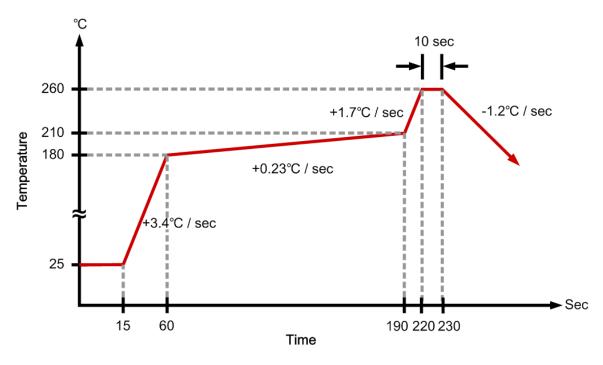
Absolute Maximum Ratings

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply Voltage	V _{CC}		0		6	V
OVP Voltage	V _{OVP}		0		28	V
LX Voltage	V _{LX}		0		28	V
EN,FB Voltage			0		6	V
Power Dissipation	P _D	SOT23-6L @T _A =25°C			455	mW
Thermal Resistance (Note1)	θ_{JA}	SOT23-6L			+220	°C / W
Junction Temperature	TJ				+150	°C
Operating Temperature	T _{OP}		-40		+85	°C
Storage Temperature	T _{ST}		-65		+150	°C
Lead Temperature		(soldering, 10 sec)			+260	°C

Note1:

 θ_{JA} is measured in the natural convection at T_A =25°C on a low effective thermal conductivity test board of JEDEC 51-3 thermal measurement standard.

IR Re-flow Soldering Curve





Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply Voltage	VIN		2.6		5.5	V
Operating Temperature Range	T _A	Ambient Temperature	-40		+85	°C

DC Electrical Characteristics (V_{CC}=3.3V, T_A=25°C,unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
System Supply Input			•			
Input Supply Range	V _{CC}		2.6		5.5	V
Under Voltage Lockout	V _{UVLO}			2.2		V
UVLO Hysteresis				0.1		V
Quiescent Current	I _{CC}	V _{FB} =0.66V, No switching		0.16		mA
Average Supply Current	I _{CC}	V _{FB} =0.55V, Switching		2.84		mA
Shutdown Supply Current	I _{CC}	V _{EN} =GND		0.1		μΑ
Oscillator						
Operation Frequency	Fosc	V _{FB} =1.0V	0.8	1.0	1.2	MH_Z
Frequency Change with Voltage	$\triangle f / \triangle V$	V _{CC} =2.7V to 5.5V		5		%
Maximum Duty Cycle	T _{DUTY}			90		%
Reference Voltage						
Feedback Voltage	V_{REF}		0.588	0.6	0.612	V
Line Regulation		V _{CC} =2.7V ~ 5.5V		0.05		% / V
Enable Control						
Enable Voltage	V _{EN}		0.96			V
Shutdown Voltage	V _{EN}				0.6	V
MOSFET	•				•	
On Resistance of Driver	R _{DS (ON)}	I _{LX} =2A		0.25		Ω
Protection						
OVP Threshold Voltage	V _{OVP}			27		V
OVP Sink Current	I _{SINK}			5		μΑ
OCP Current	I _{OCP}		2		2.6	Α
Adjustable OCP Current	I _{OCP}	With External Resistor : 10k~100k	0.5		2.6	Α
OTP Temperature	T _{OTP}			+150		°C



Function Description

Operation

The AP8660 is a current mode boost converter. The constant switching frequency is 1MHz and operates with pulse width modulation (PWM). Build-in 26V / 2A MOSFET provides a high output voltage. The control loop architecture is peak current mode control; therefore slope compensation circuit is added to the current signal to allow stable operation for duty cycles larger than 50%.

Soft Start Function

Soft start circuitry is integrated into AP8660 to avoid inrush current during power on. After the IC is enabled, the output of error amplifier is clamped by the internal soft-start function, which causes PWM pulse width increasing slowly and thus reducing input surge current.

Current Limit Program

A resistor between OC and GND pin programs peak switch current. The resistor value should be between 10k and 100k. The current limit will be set from 2.5A to 0.5A. Keep traces at this pin as short as possible. Do not put capacitance at this pin. To set the over current trip point according to the following equation:

$$I_{OCP} = \frac{48000}{R3}$$

Over Voltage Protection (OVP)

In some condition, the resistive divider may be unconnected, which will cause PWM signal to operate with maximum duty cycle and power switch voltage is boosted higher and higher. The power MOSFET will be turned off immediately, when the power switch voltage exceeds the OVP threshold level. The AP8660's OVP threshold is 27V.

Over Temperature Protection (OTP)

AP8660 will turn off the power MOSFET automatically when the internal junction temperature is over 150°C. The power MOSFET wake up when the junction temperature drops 30°C under the OTP threshold temperature.

Output Disconnect

When power on and the EN pin will be pulled high. The AP8660 start up and operates. The external PMOS is turned on and current through it for output loading. While output loading is increase, output voltage is drop. When the FB pin voltage is under 0.3V, the EN pin sinks 20µA current, the external PMOS will be turn off. The output short condition will be disconnected.



Application Information

Inductor Selection

Inductance value is decided based on different condition. 4.7 to 22µH inductor value is recommended for general application circuit. There are three important inductor specifications, DC resistance, saturation current and core loss. Low DC resistance has better power efficiency. Also, it avoid inductor saturation which will cause circuit system unstable and lower core loss at 1 MHz.

Capacitor Selection

The output capacitor is required to maintain the DC voltage. Low ESR capacitors are preferred to reduce the output voltage ripple. Ceramic capacitor of X5R and X7R are recommended, which have low equivalent series resistance (ESR) and wider operation temperature range.

Diode Selection

Schottky diodes with fast recovery times and low forward voltages are recommended. Ensure the diode average and peak current rating exceed the average output current and peak inductor current. In addition, the diode's reverse breakdown voltage must exceed the output voltage.

Output Voltage Programming

The output voltage is set by a resistive voltage divider from the output voltage to FB. The output voltage is:

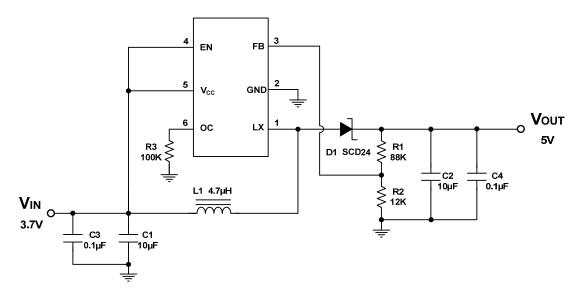
$$V_{OUT} = 0.6V \left(1 + \frac{R1}{R2}\right)$$

Layout Considerations

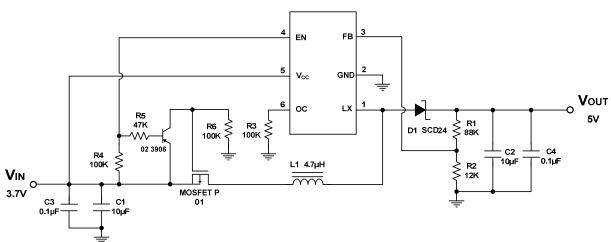
- The power traces, consisting of the GND trace, the LX trace and the V_{CC} trace should be kept short, direct and wide.
- 2. LX \ L and D switching node, wide and short trace to reduce EMI.
- 3. Place C_{IN} near V_{CC} pin as closely as possible to maintain input voltage steady and filter out the pulsing input current.
- 4. The resistive divider R1and R2 must be connected to FB pin directly as closely as possible.
- 5. FB is a sensitive node. Please keep it away from switching node, LX.
- 6. The GND of the IC, C_{IN} and C_{OUT} should be connected close together directly to a ground plane.



Typical Application



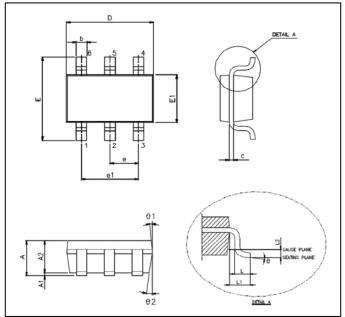
General Boost Converter



SCP Detect and Load Disconnect



Package Outline SOT23-6L



Unit: mm

Symbols	Min. (mm)	Max. (mm)		
А	1.050	1.450		
A1	0.050	0.150		
A2	0.900	1.300		
b	0.300	0.500		
С	0.080	0.220		
D	2.900	BSC		
E	2.800 BSC			
E1	1.600 BSC			
е	0.950 BSC			
e1	1.900 BSC			
L	0.300	0.600		
L1	0.600 REF			
L2	0.250 BSC			
θ°	0°	8°		
θ1°	3°	7°		
θ2°	6°	15°		

Note:

- 1. Package dimensions are in compliance with JEDEC outline: MO-178 AB.
- 2. Dimension "D" does not include molding flash, protrusions or gate burrs.
- 3. Dimension "E1" does not include inter-lead flash or protrusions.